

Physics 8510

Problem Set 8

1) GaAs has a conduction band that can be described near the band edge by an expression in the form $E(k) = \hbar^2 k^2 / 2m^*$, where $m^* = 0.067 m_0$. An electric field of 10 kV/cm (along the x-axis is applied at time $t = 0$ to an electron at the bottom of the conduction band. What is the energy of the electron after a time interval of 1, 2, 10 picoseconds. (Band structure is periodic in the reciprocal lattice space. If the electron exceeds the zone edge k value, it will undergo a reflection by a RLV-Reciprocal Lattice Vector.)

2) Consider a square lattice in 2-d with a background potential $U(x, y) = U_0 \cos 2\pi x/a \cos 2\pi y/a$, where $U_0 = 2.0$ eV. Set up the 2×2 secular equation to calculate the bandgap at the point $(\pi/a, \pi/a)$ of the Brillouin zone. (Hint: Potential energy contains the 4 reciprocal lattice vectors)

3) In GaAs, once the channel dimensions are less than 1000 \AA , much of the transport occurs without scattering. In such ballistic transport, the electron climbs up along the E vs K diagram in accordance with the effective Newton's equation of motion.

Assume a parabolic band relation $E = \hbar^2 k^2 / 2m^*$ with $m^* = 0.067 m_0$. Calculate the electron transit time and final energy for a transit length of $0.1 \mu\text{m}$ and an electric field of 10^3 V/cm and 10^5 V/cm.

4) Consider a 1-d solid of length $L = Na$ made up of N diatomic molecules, the interatomic spacing within a molecule is b ($b < a/2$). The centers of adjacent molecules are a distance a apart. Potential energy can be represented as a sum of delta functions centered on each atom with A a positive quantity and $n = 0, 1, 2, \dots, N-1$. (shown below)

$$V = -A \sum_{n=0}^{N-1} [\delta(x-na+b/2) + \delta(x-na-b/2)]$$

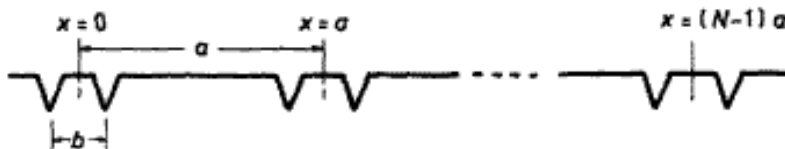
(a) Consider free electrons ($V = 0$) in the solid and periodic boundary conditions. Derive the allowed values of the electron wave vectors k , and normalize the wave function.

(b) Expressing the potential as a Fourier series $V = \sum V_G e^{iGx}$, find the allowed values of G and the coefficients V_G .

(c) Assuming A to be small, show that for certain values of k there are energy gaps. Derive a formula for the gaps and show in particular that the gap energy at the top of the first zone is proportional to $\cos(\pi b / a)$. [Hint: use the result of (b)]

(d) Derive an expression for the number of states that are in the first zone. If each atom has one electron, will the substance be a conductor or an insulator? (Hint: Each state corresponds to 2 spin values. N diatomic molecules give $2N$ atoms each atom contributes one electron. If the first zone states are not completely full it will be a conductor, if completely full an insulator.)

(e) If $b = a/2$, how will the answers (a-d) change?



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